# BGM781N11

**GPS Front-End Module** 

RF & Protection Devices



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Revision History: GPS Front-End Module, Rev.3.2

**Previous Version: 2009-10-30, Rev.3.1** 

Page	Subjects (major changes since last revision)					
10	Package pin tolerances changed from 35µm to 50µm					



### **GPS Front-End Module**

### **BGM781N11**

### 1 GPS Front-End Module

### **Features**

Operating frequency: 1575.42 MHz

· High Gain: 18.6 dB

• Low Noise Figure: 1.7 dB

· Low current consumption: 3.3 mA

• Out-of-band rejection in cellular bands: 80 dBc

• Input compression point in cellular bands: 20 dBm

Supply voltage: 1.5 V to 3.6 V

Tiny TSNP-11-2 leadless package

• RF input internally pre-matched to 50  $\Omega$ 

• RF output internally matched to 50  $\Omega$ 

HBM ESD capability of all pins: 2 kV

IEC ESD contact discharge of RF input pin: 8 kV

Only 2 external SMD parts

RoHS compliant package (Pb-free)

# TSNP11-2.vsd

TSNP-11-2 Package top view (2.5 x 2.5 x 0.73 mm³)

**Application** 

1575.42 MHz GPS, Galileo, GPS phones, personal navigaton devices



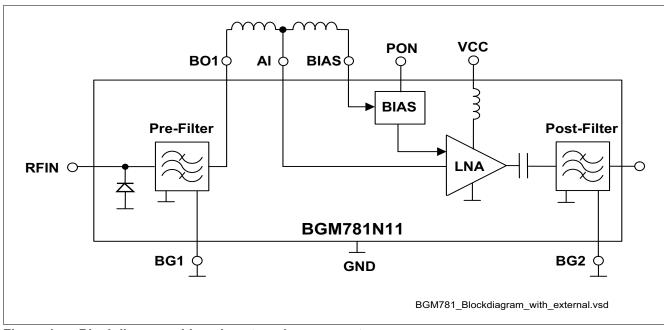


Figure 1 Blockdiagram with main external components

Data Sheet 4 Rev.3.2, 2010-10-28



Description

# 2 Description

The BGM781N11 is a combination of a low-insertion-loss pre-filter with Infineon's high performance low noise amplifier (LNA) and a high-attenuation post-filter for Global Positioning System (GPS) applications. Through the low insertion loss of the filters, the BGM781N11 provides 18.6 dB gain, 1.7 dB noise figure and high linearity performance. In addition BGM781N11 provides very high out-of-band attenuation in conjunction with a high input compression point. Its current consumption is as low as 3.3 mA. It operates over the 1.5 V to 3.6 V supply voltage range.

Туре	Package	Marking
BGM781N11	TSNP-11-2	M781

### **Pin Definition and Function**

Table 1 Pin Definition and Function

Pin No.	Symbol	Function			
1	BG2	Optional Output-Filter GND			
2	PON	Power On/Off			
3	VCC	Power Supply			
4	n.c.	not used			
5	RFIN	RF Input			
6	BG1	Input-Filter GND			
7	BO1	Input-Filter Output			
8	Al	LNA Input			
9	BIAS	BIAS			
10	RFOUT	RF Output	RF Output		
11	GND	Package Middle Island			

### **Maximum Ratings**

Table 2 Maximum Ratings

Parameter <sup>1)</sup>	Symbol	Value	Unit	Note / Test Condition
Voltage at pin BG2 to GND	$V_{BG2}$	-11	V	
Voltage at pin PON to GND	$V_{PON}$	-0.33.6	V	
Voltage at pin VCC to GND	$V_{\sf CC}$	-0.33.6	V	
Voltage at pin RFIN to GND	$V_{RFIN}$	-33	V	
Voltage at pin BG1 to GND	$V_{BG1}$	-33	V	
Voltage at pin B01 to GND	$V_{BO1}$	-33	V	
Voltage at pin AI to GND	$V_{Al}$	-0.30.9	V	
Voltage at pin BIAS to GND	$V_{BIAS}$	-0.30.9	V	
Voltage at pin RFOUT to GND	$V_{RFOUT}$	-33	V	
Current into pin VCC	$I_{VCC}$	25	mA	
RF input power inband	$P_{IN}$	3	dBm	Continuous wave signal $f$ = 1575.42 MHz 50 ohm source and load impedances



**Description** 

Table 2 Maximum Ratings (cont'd)

Parameter <sup>1)</sup>	Symbol	Value	Unit	Note / Test Condition
RF input power out of band	$P_{IN,OOB}$	21		Continuous wave signal $f = 50 - 1460$ MHz and 1710 - 4000 MHz 50 ohm source and load impedances
Total power dissipation	$P_{tot}$	90	mW	
Junction temperature	$T_{J}$	150	°C	
Ambient temperature range	$T_{A}$	-40 85	°C	
Storage temperature range	$T_{STG}$	-65 85	°C	
ESD capability HBM of all pins, with pin 6 and GND middle island pin 11 tied together	$V_{ESD1}$	2	kV	according to JESD22A-114
ESD contact discharge capability of RF input pin 5	$V_{ESD2}$	8	kV	according to IEC61000-4-2

<sup>1)</sup> All voltages refer pin-to-pin, unless otherwise specified.



**Electrical Characteristics** 

### 3 Electrical Characteristics

Table 3 Electrical Characteristics:  $T_A$  = 25 °C,  $V_{CC}$  = 1.8 V,  $V_{PON,ON}$  = 1.8 V,  $V_{PON,OFF}$  = 0 V<sup>1)</sup>

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Тур.	Max.		
Supply Voltage	$V_{\sf CC}$	1.5	1.8	3.6	V	
Supply Current	$I_{\sf CC}$	-	3.3	-	mA	ON-Mode
		-	0.2	3	μΑ	OFF-Mode
Power On Control Voltage	$V_{pon}$	1.0	-	Vcc	V	ON-Mode
		0	-	0.4	V	OFF-Mode
Power On Control Current	$I_{pon}$	-	5	-	μΑ	ON-Mode
		-	-	1	μΑ	OFF-Mode
Power Gain Settling Time <sup>2)</sup>	$t_{S}$	-	5	-	μS	OFF- to ON-Mode
		-	5	-	μS	ON- to OFF-mode
Passband Parameters @ f = 1575.42 MHz						
Insertion Power Gain	$ S_{21} ^2$	17.1	18.6	-	dB	
Noise Figure <sup>3)</sup>	NF	-	1.7	2.3	dB	$Z_{\rm S}$ = 50 $\Omega$
Input Return Loss	$RL_{\sf in}$	-	12	-	dB	
Output Return Loss	$RL_{out}$	-	15	-	dB	
Reverse Isolation	$1/ S_{12} ^2$	-	40	-	dB	
Inband Input 3rd Order Intercept Point	IIP <sub>3</sub>	-	-7	-	dBm	$f_1 = 1575.42 \text{ MHz}$ $f_2 = f_1 + 1 \text{ MHz}$
Inband Input 1 dB Compression Point	IP <sub>1dB</sub>	-	-15	-	dBm	f <sub>1</sub> = 1575.42 MHz
Out-of-band Input 1 dB Compression Point	<i>IP</i> <sub>1dB_900M</sub>	-	20	-		f <sub>1</sub> = 900 MHz
Out-of-band Input 1 dB Compression Point	<i>IP</i> <sub>1dB_1710M</sub>	-	20	-		f <sub>1</sub> = 1710 MHz
Stopband Parameters						
Rejection <sup>4)</sup>	Rej <sub>900M</sub>	-	90	-	dBc	f = 806 MHz - 928 MHz
Rejection <sup>4)</sup>	<i>Rej</i> <sub>1800M</sub>	-	80	-	dBc	f = 1710 MHz - 1980 MH
Rejection <sup>4)</sup>	<i>Rej</i> <sub>2400M</sub>	-	72	-	dBc	f = 2400 MHz - 2500 MH
Stability	k	-	>1	-		f = 20 MHz - 20 GHz

<sup>1)</sup> Specification based on performance as measured on BGM781N11application board shown in Figure 3 and including PCB losses (unless noted otherwise)

<sup>2)</sup> To be within 1 dB of the final gain OFF- to ON-mode; to be within 3 dB of the final gain ON- to OFF-mode

<sup>3)</sup> PCB and connector losses subtracted, verified on AQL base

<sup>4)</sup> Rejection= $|(1/|S_{21}|^2)$  at stopband frequency  $|+|(1/|S_{21}|^2)$  at 1575.42 MHz



**Application Information** 

# 4 Application Information

### 4.1 Application Circuit

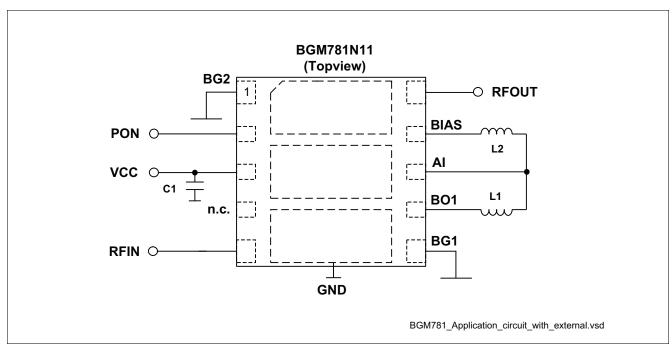


Figure 2 Application circuit with external components

Table 4 Bill of Materials

Name	Value	Package	Manufacturer	Function
C1	1 μF	0402	Various	Supply voltage filtering (optional)
L1	3.6 nH	0402	muRata LQG15HS	Input matching
L2	33 nH	0402	muRata LQG15HS	Bias
N1	BGM781N11	TSNP-11-2	Infineon	GPS FE Module



**Application Information** 

# 4.2 Application Board

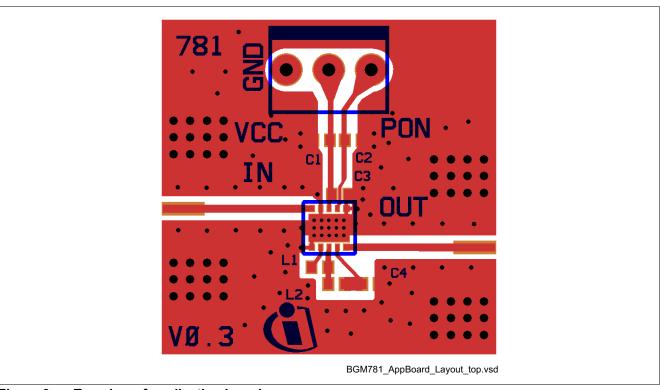


Figure 3 Top view of application board

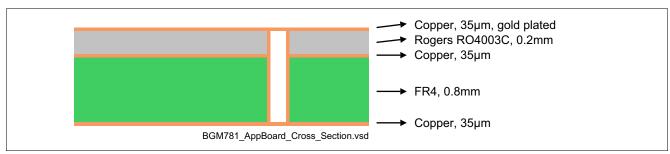


Figure 4 Cross section view of application board



**Package Information** 

# 5 Package Information

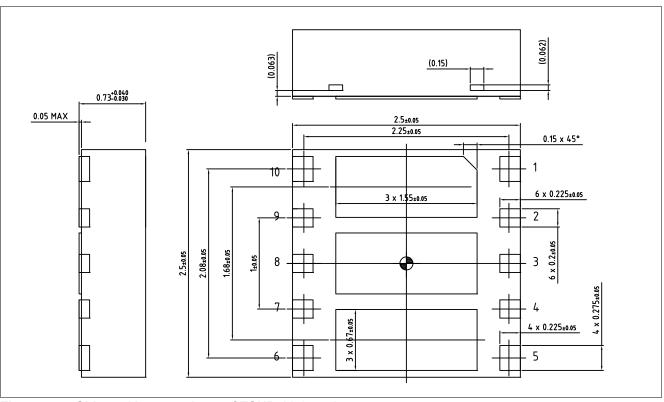


Figure 5 Side and bottom views of TSNP-11-2 package

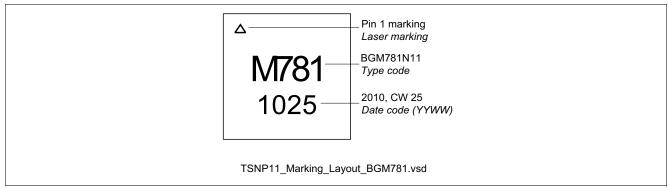


Figure 6 Marking layout



### **Package Information**

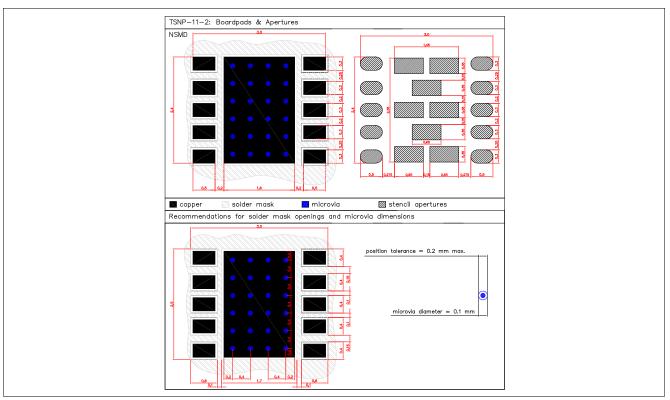


Figure 7 Recommended TSNP-11-2 footprint for optimum RF performance

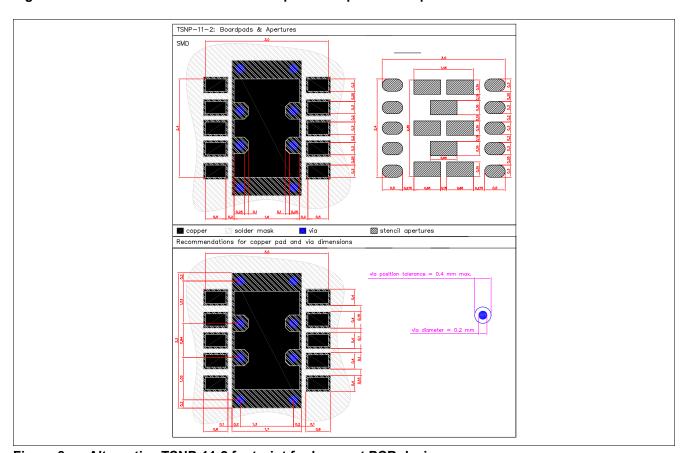


Figure 8 Alternative TSNP-11-2 footprint for low cost PCB designs

**Packing Information** 

# 6 Packing Information

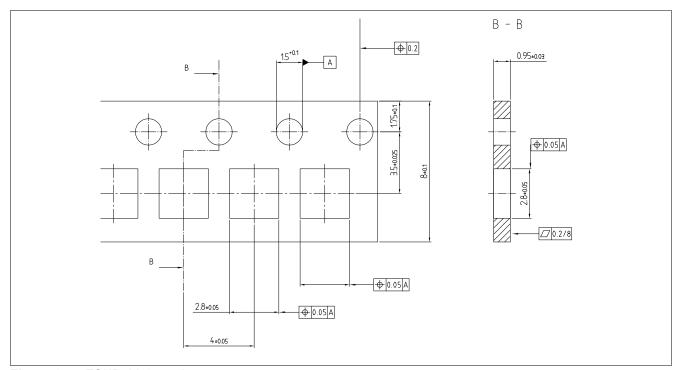


Figure 9 TSNP-11-2 carrier tape

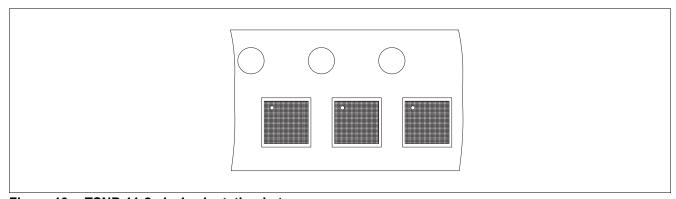


Figure 10 TSNP-11-2 pin 1 orientation in tape